









PRODUCT DATASHEET



- ► PLCC6 SMD with IC
- ➤ 3535IC 1.47t Series
- ► Red/Green/Blue

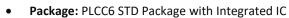
N0M67S12IC







FEATURES:



3535 IC-Integrated Compliant

Forward Current: 12mA

Forward Voltage (typ.): +4.5~+5.5V

Luminous Intensity (typ.): 350/1200/270mcd* Mixed White Luminous Intensity (typ.): 1800mcd

Colour: Red/Green/Blue

Dominant Wavelength (typ.): 622/527/467nm

Viewing Angle: 120°

Operating Temperature: -40~+85°C

Storage Temperature: -40~+105°C

IC Feature: Serial data transmission signal by dual-wire DATA & CLK lines. One pixel contains R, G, and B colour that each can achieve 256 level brightness grayscales, which forms 16,777,216 combination colours. Support sleep/wake-up mode. In sleep mode, the LED current is lower than 5µA.

- **Soldering methods:** IR reflow soldering
- MSL Level: acc. to JEDEC J-STD-020E Level 5
- Packing: 12mm tape with max.1300pcs/reel, Ø180mm (7")

* in order of Red/Green/Blue

APPLICATIONS:

- Telecommunication
- Home Appliance
- **Decoration Lighting**
- Full Colour LED Strip
- **Gaming Device**

Support sleep/wake up mode. In sleep mode the LED's current was lower than 5µA



CHARACTERISTICS:

Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
IC Power Supply Voltage	V_{DD}	max.6.5	V
Rate of Data Signal	Fclk	15	MHz
Max. LED Output Current	Іомах	12/channel	mA
Power Dissipation	P _D	max.400	mW
Operating Temperature	TOPR	-40~+85	°C
Storage Temperature	T _{STG}	-40~+105	°C
Electrostatic Discharge (HBM) acc. To ANSI/ESDA/JEDEC JS-001	ESD	6000	V
Soldering Temperature (10s)	T _{SD}	245	°C

^{*} in order of Red/Green/Blue

Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Symbol		Values	Unit	Test	
- Fai ailletei	raiailietei		Min.	Тур.	Max.	Offic	Condition
Forward Voltage		V _F	4.5	5.0	5.5	V	
	R			350			
Luminous Intensity	G	lv		1200		med	I _F =12mA
	В	IV		270		mcd	
Mix White	W			1800			
	R		615		630		
Dominant Wavelength	G	λ _d	520		535	nm	I _F =12mA
	В		460		475		
X Colour Coordinate				0.2850			1 12 1
Colour Coordinate	Υ			0.2850			I _F =12mA
Viewing Angle		2θ _{1/2}		120		deg	I _F =12mA

^{1.} Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.

^{2.} $2\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

^{3.} The dominant wavelength, λ_d is derived from CIE chromaticity diagram and represents the single wavelength which defines the colour of the device. Peak Emission Wavelength Tolerance is ± 1 nm.



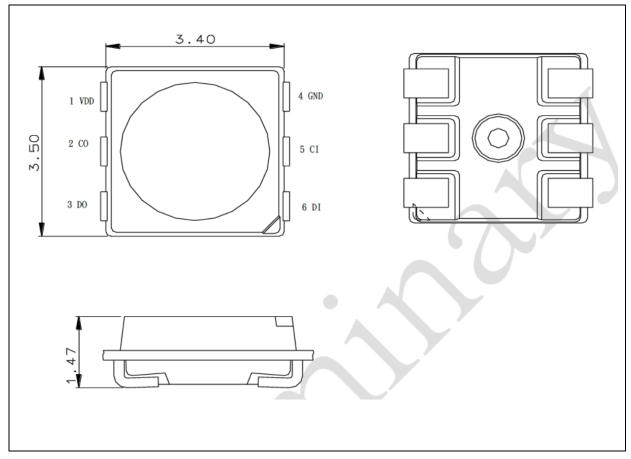
Electrical & Optical Characteristics (Ta=25°C, V_{DD}=5V)

Parameter		Values	Unit	Test		
raiailletei	Symbol	Min. Typ.		Max.	Offic	Condition
Supply Voltage	V_{DD}	4.5	5.0	5.5	V	
Innut Voltage Lovel	V _{IH}	2.7		V _{DD} +0.4	V	
Input Voltage Level	VIL	-0.4		1.0	V	
Clock High Level Width	Тськн	30			ns	
Clock Low Level Width	T _{CLKL}	30			ns	
Data Set-Up Time	T _{SETUP}	10			ns	
Data Hold Time	T _{HOLD}	5			ns	
Working Current (IC)	I _{DD}			2	mA	I _{out} =OFF
Static Current	I _{sleep}			5	μΑ	Sleep Mode



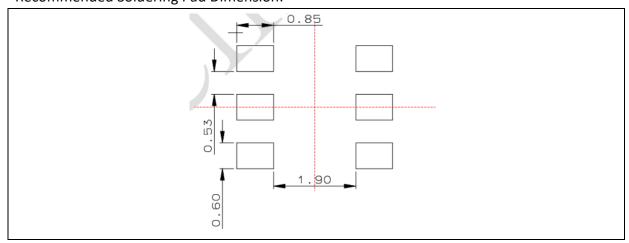
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.2mm, unless otherwise noted.

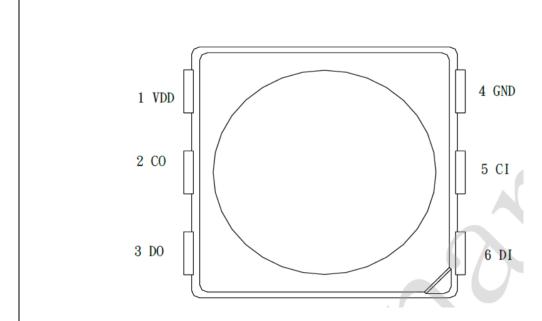
Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



PIN CONFIGURATION:



No.	Symbol	Function Description
1	VDD	Supply Voltage
2	СО	Clock Output
3	DO	Data Output
4	GND	Ground
5	CI	Clock Input
6	DI	Data Input

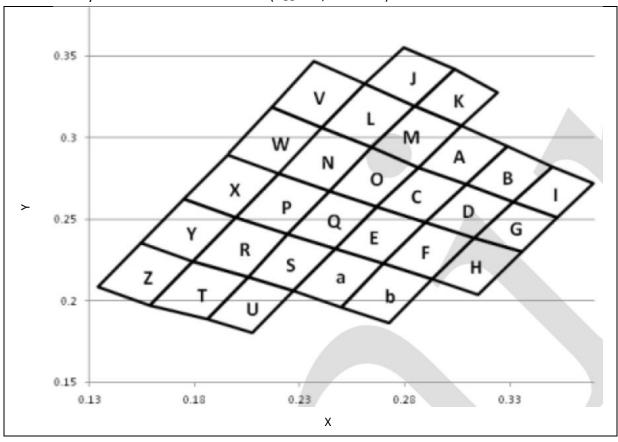


BINNING GROUPS:

Luminous Intensity Classifications (V_{DD}=5V; I_F=12mA*3):

Со	de	Min.	Max.	Unit
	15	1000	1300	
NAiv Mhita	16	1300	1700	mad
Mix White	17	1700	2200	mcd
	18	2200	2800	

Chromaticity Coordinate Classifications (V_{DD}=5V; I_F=12mA):



	1	1	2		3		4	
	Х	Υ	Х	Υ	Х	Υ	Х	Υ
А	0.3070	0.3072	0.3287	0.2948	0.3091	0.2712	0.2865	0.2819
В	0.3287	0.2948	0.3504	0.2824	0.3318	0.2605	0.3091	0.2712
С	0.2865	0.2819	0.3091	0.2712	0.2899	0.2482	0.2667	0.2578
D	0.3091	0.2712	0.3318	0.2605	0.3132	0.2387	0.2899	0.2482

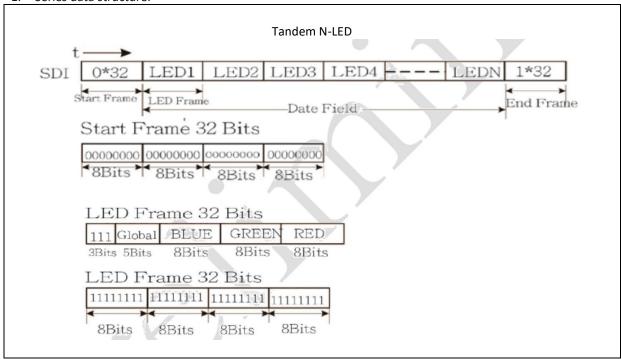


	1	1	2	2	3	3	4		
	Х	Υ	Х	Y	Х	Υ	Х	Υ	
E	0.2667	0.2578	0.2899	0.2482	0.2700	0.2227	0.2470	0.2320	
F	0.2899	0.2482	0.3132	0.2387	0.2930	0.2134	0.2700	0.2227	
G	0.3318	0.2605	0.3424	0.2513	0.3358	0.2299	0.3132	0.2387	
Н	0.2930	0.2134	0.3132	0.2387	0.3358	0.2299	0.3150	0.2040	
I	0.3318	0.2605	0.3504	0.2824	0.3695	0.2719	0.3524	0.2513	
J	0.2609	0.3332	0.2797	0.3550	0.3036	0.3420	0.2849	0.3196	
К	0.2851	0.3196	0.3036	0.3420	0.3243	0.3280	0.3068	0.3072	
L	0.2406	0.3064	0.2609	0.3332	0.2849	0.3196	0.2643	0.3940	
М	0.2643	0.2940	0.2849	0.3196	0.3068	0.3072	0.2865	0.2819	
N	0.2200	0.2783	0.2406	0.3064	0.2643	0.2940	0.2444	0.2672	
0	0.2444	0.2672	0.2643	0.2940	0.2865	0.2819	0.2667	0.2578	
Р	0.2200	0.2783	0.1996	0.2513	0.2244	0.2407	0.2444	0.2672	
Q	0.2444	0.2672	0.2244	0.2407	0.2471	0.2320	0.2669	0.2579	
R	0.1996	0.2513	0.1792	0.2243	0.2056	0.2148	0.2244	0.2407	
Т	0.1792	0.2243	0.1588	0.1973	0.1862	0.1886	0.2056	0.2148	
U	0.2056	0.2148	0.1862	0.1886	0.2075	0.1802	0.2273	0.2061	
Х	0.1960	0.2894	0.1752	0.2624	0.1996	0.2513	0.2200	0.2783	
Υ	0.1752	0.2624	0.1548	0.2354	0.1792	0.2243	0.1996	0.2513	
Z	0.1548	0.2354	0.1344	0.2084	0.1588	0.1973	0.1792	0.2243	
S	0.2244	0.2407	0.2056	0.2148	0.2273	0.2061	0.2471	0.2320	
а	0.2471	0.2320	0.2273	0.2061	0.2498	0.1959	0.2700	0.2227	
b	0.2700	0.2227	0.2498	0.1959	0.2728	0.1866	0.2930	0.2134	
V	0.2169	0.3188	0.2369	0.3468	0.2609	0.3332	0.2406	0.3064	
W	0.1963	0.2907	0.2169	0.3188	0.2406	0.3064	0.2200	0.2783	



FUNCTION DESCRIPTION:

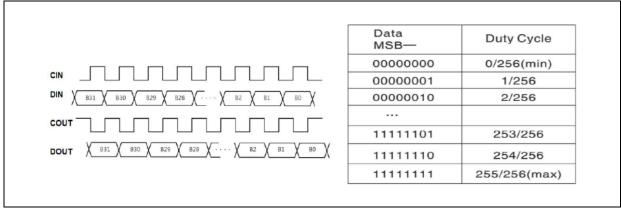
1. Series data structure:



2. Dim 5-Bit (level 32) brightness adjustment (simultaneous control of OUTR/OUTG/OUTB three port current):

Data	Driving Current
MSB←→LSB	
00000	0/31
00001	1/31
00010	2/31
11110	30/31
11111	31/31(max)

3. PWM input/output signal relations:





4. Sleep and power saving mode:

LED supports sleep/wake-up modes for power saving purposes. After the IC receives 24-bits 0's BGR data (that is B[7:0]=8h00, G[7:0]=8h00, R[7:0]=8h00), in the meantime, both of the data in 3-bits FLAG and 5-bits DIMMING is 8h'A0' (that is FLAG[2:0]=3b101 and DIMMING[4:0]=5b00000), the IC will entre sleep mode, its current is about 1μ A.

The IC will wake-up from sleep mode once receiving the new data with the data of FLAG[2:0], DIMMING[4:0] is not 8h'A0'; after wake-up, all sleeping circuits in IC return to normal working mode within 1ms. Since it takes 1ms for a sleeping IC to return to normal function mode, it is recommended for a host to wait for 1ms to send display data and command after issuing a wake-up command.

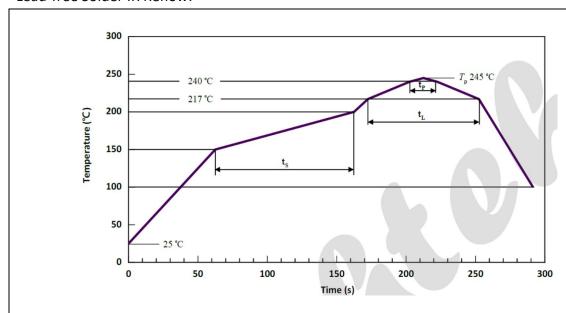


In case 2, while lamp 2 is under sleep mode, in the following data transfer process, the state of lamp 2 will be not changed as long as the 32-bits data for lamp 2 is received with data of FLAG[2:0] and DIMMING[4:0] being 8h"A0". It means lamp 2 will keep in sleep mode as well. In this situation, lamp 2 can pass through the remaining data to lamp 3 (32-bits) to change the display data of lamp 3. In other words, the sleeping chip is able to pass the data to the next chips.



RECOMMENDED SOLDERING PROFILE:

Lead-free Solder IR Reflow:



Profile Feature	Symbol	Pb	b-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up Rate to Preheat			2	3	v Is
25 °C to 150 °C			2	3	K/s
Time t₅	ts	60	100	120	
T _{Smin} to T _{Smax}	LS	00	100	120	S
Ramp-up Rate to Peak			2	3	K/s
T _{Smax} to T _P			2		NJS
Liquids Temperature	TL		217		°C
Time Above Liquids Temperature	tL		80	100	S
Peak Temperature	Тр		245	260	°C
Time Within 5 °C of the Specified Peak Temperature T _P - 5 K	Тр			10	s
Ramp-Down Rate			3	4	K/s
T _P to 100 °C			3	4	N/S
Time				480	5
25 °C to T _P				400	3

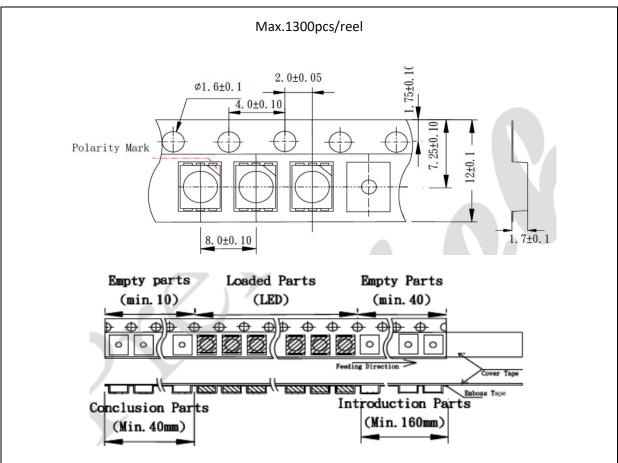
Note:

- 1. We recommend the reflow temperature 240°C (±5°C). The maximum soldering temperature should be limited to 245°C.
- 2. Maximum reflow soldering: 1 time.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



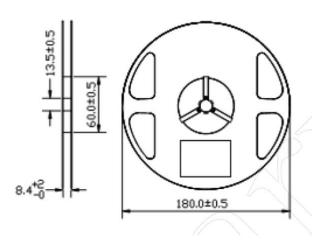
PACKING SPECIFICATION:

Reel Dimension:



Notes:

- 1. Empty component pockets are sealed with top cover tape
- 2. The cathode is oriented towards the tape sprocket hole in accordance with ANSI/EIA RS-481 specifications
- 3. The remainder packing in multiples of 500pcs.





PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

Humidity: 60% R.H. Max.

• Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within 24 hours. Otherwise, they should be kept in a damp-proof box with descanting agent stored at R.H.<10% and apply baking before use.

Over-Current Proof:

Must apply resistors for protection otherwise slight voltage shift will cause big current change and burnout will happen.

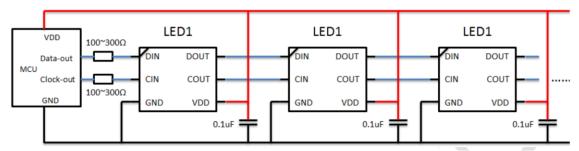
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 6hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Typical Application Circuit:



Note:

When the first LED is connected to the MCU, a resistance R is needed in series between its signal input line and the MCU. The size of R depends on the number of cascade beads. The more cascades, the smaller resistance R is used. It is generally recommended that the value be between 100-1K. Usually the recommended value is around 300 R. In order to make the LEDs work more stably, a parallel capacitor is needed between VDD and GND of each LED.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.



REVISION RECORD:

Version	Date	Summary of Revision
A1.0	15/09/2024	Datasheet set-up.